

Pch 100V 13A Power MOSFET

V_{DSS}	-100V
R _{DS(on)} (Max.)	200m $Ω$
I _D	-13A
P_D	20W

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating; RoHS compliant
- 6) 100% Avalanche tested

Application

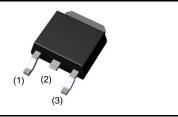
Switching Power Supply

Automotive Motor Drive

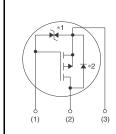
Automotive Solenoid Drive

Outline

CPT3 (SC-63) <SOT-428>



•Inner circuit



- (1) Gate
- (2) Drain
- (3) Source
- *1 ESD PROTECTION DIODE
- *2 BODY DIODE

Packaging specifications

	Packaging	Taping
	Reel size (mm)	330
Typo	Tape width (mm)	16
Туре	Basic ordering unit (pcs)	2,500
	Taping code	TL
Marking		131P10

•Absolute maximum ratings($T_a = 25$ °C)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V_{DSS}	-100	V
Continuous drain current	T _c = 25°C	I _D *1	±13	А
	T _c = 100°C	I _D *1	±7.0	А
Pulsed drain current	I _{D,pulse} *2	±52	А	
Gate - Source voltage		V_{GSS}	±20	V
Avalanche energy, single pulse		E _{AS} *3	11.9	mJ
Avalanche current		I _{AR} *3	-13	А
$T_c = 25$ °C		P _D	20	W
Power dissipation $T_a = 25^{\circ}C$		P _D	0.85	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

●Thermal resistance

Parameter	Symbol	Values			Unit
raiametei	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - ambient	R _{thJC}	-	ı	6.25	°C/W

•Electrical characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	ter Symbol Conditions —		Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$, $I_D = -1mA$	-100	ı	ı	V
		$V_{DS} = -100V, V_{GS} = 0V$			1	
Zoro goto voltago droin gurrant		T _j = 25°C	-	-	–1	μА
Zero gate voltage drain current	I _{DSS}	$V_{DS} = -100V, V_{GS} = 0V$			-100	
		T _j = 125°C	-	-		
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±10	μΑ
Gate threshold voltage	V _{GS (th)}	$V_{DS} = -10V, I_{D} = -1mA$	-1	-	-2.5	V
		$V_{GS} = -10V, I_D = -6.5A$	-	135	200	
		$V_{GS} = -4.5V, I_D = -6.5A$	-	150	220	
Static drain - source on - state resistance	$R_{DS(on)}^{}^{\star 4}}$	$V_{GS} = -4.0V, I_D = -6.5A$	-	155	230	mΩ
		$V_{GS} = -10V, I_D = -13A$		250	250	
		T _j = 125°C	-	250	350	
Forward transfer admittance	g _{fs}	$V_{DS} = -10V, I_{D} = -13A$	10	20	1	S

• Electrical characteristics ($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai ii e lei	Syllibol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C _{iss}	$V_{GS} = 0V$	ı	2400	ı	
Output capacitance	C _{oss}	$V_{DS} = -25V$	-	100	1	pF
Reverse transfer capacitance	C_{rss}	f = 1MHz	-	65	1	
Turn - on delay time	t _{d(on)} *4	$V_{DD} \simeq -50V, V_{GS} = -10V$	-	20	1	
Rise time	t _r *4	$I_D = -6.5A$	-	25	1	no
Turn - off delay time	t _{d(off)} *4	$R_L = 7.68\Omega$	-	70	-	ns
Fall time	t _f *4	$R_G = 10\Omega$	-	60	-	

• Gate Charge characteristics ($T_a = 25$ °C)

Parameter	Symbol	Conditions		Values		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q_g^{*4}	$V_{DD} \simeq -50V$	-	40	-	
Gate - Source charge	Q _{gs} *4	$I_D = -13A$	-	6	-	nC
Gate - Drain charge	Q _{gd} *4	$V_{GS} = -10V$	-	6	-	
Gate plateau voltage	V _(plateau)	$V_{DD} \simeq -50V, I_D = -13A$	-	-3.2	-	V

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

Parameter	Symbol	Conditions	no		Values		
Parameter	Symbol	ol Conditions -		Тур.	Max.	Unit	
Continuous source current	l _S *1	T _c = 25°C	-	1	-13	А	
Pulsed source current	I _{SM} *2	1 c = 25 C	-	-	-52	Α	
Forward voltage	V _{SD} *4	$V_{GS} = 0V, I_{S} = -13A$	-	-	-1.2	V	
Reverse recovery time	t _{rr} *4	I _S = −13A	-	60	-	ns	
Reverse recovery charge	Q _{rr} *4	di/dt = -100A/μs	-	160	-	μС	

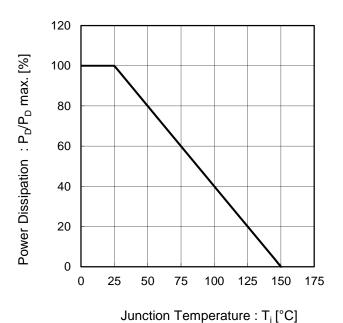
^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10 μ s, Duty cycle \leq 1%

^{*3} L $^{\simeq}$ 100 μ H, V_{DD} = -50V, Rg = 10 Ω , starting T_{j} = 25°C

^{*4} Pulsed

Fig.1 Power Dissipation Derating Curve



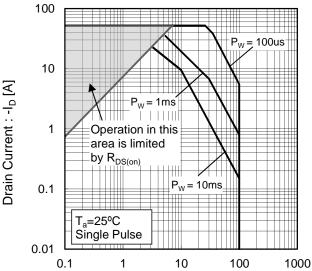
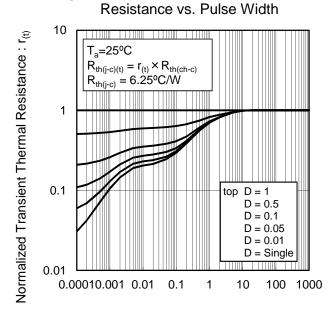


Fig.2 Maximum Safe Operating Area

Drain - Source Voltage : -V_{DS} [V]

Fig.3 Normalized Transient Thermal



Pulse Width : $P_W[s]$

Fig.4 Avalanche Current vs Inductive Load

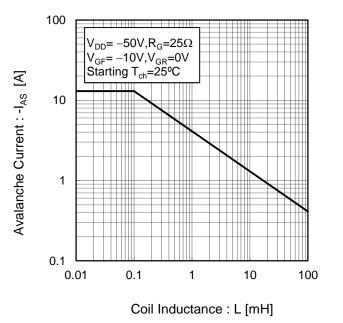
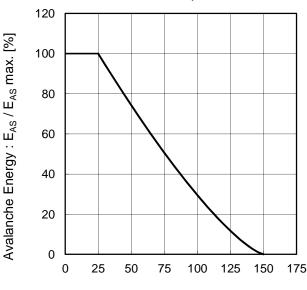
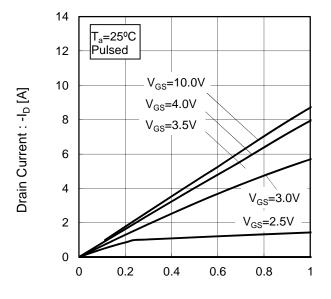


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature



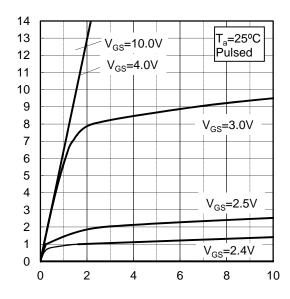
Junction Temperature : T_i [°C]

Fig.6 Typical Output Characteristics(I)



Drain - Source Voltage : - V_{DS} [V]

Fig.7 Typical Output Characteristics(II)



Drain - Source Voltage : -V_{DS} [V]

Drain Current: -I_D [A]

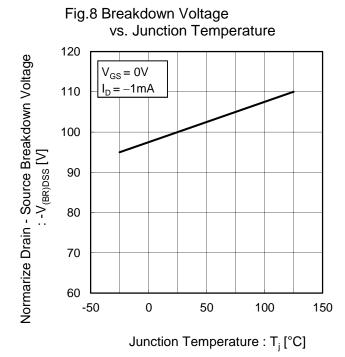
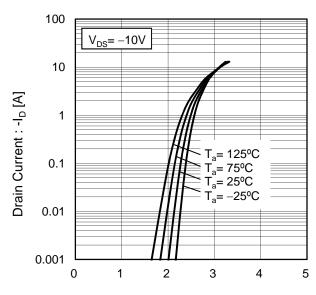


Fig.9 Typical Transfer Characteristics



Gate - Source Voltage : $-V_{GS}[V]$

Fig.10 Gate Threshold Voltage vs. Junction Temperature

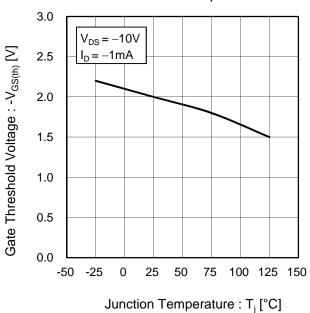
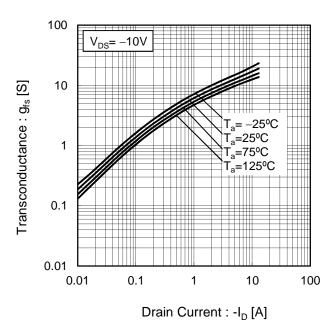


Fig.11 Transconductance vs. Drain Current



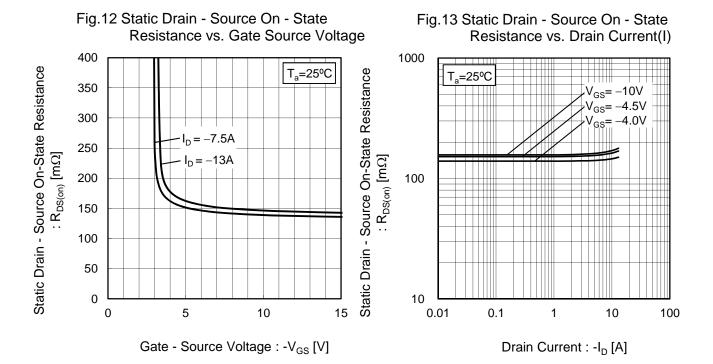
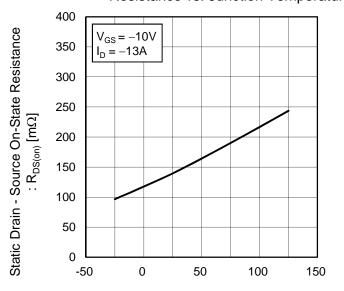


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature



Junction Temperature : T_j [°C]

Resistance vs. Drain Current(II)

1000

V_{GS}= -10V

T_a=125°C

T_a=75°C

T_a=-25°C

T_a=-25°C

T_a=-25°C

T_a=-25°C

T_a=-10V

T_a=125°C

T_a=-10V

T_a=-10

Drain Current: -I_D [A]

Fig.15 Static Drain - Source On - State

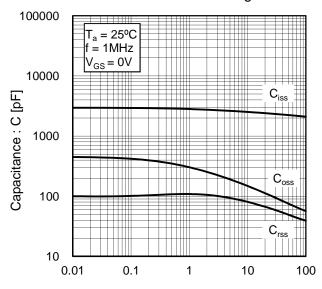
Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III) 1000 T_a=125°C Static Drain - Source On-State Resistance =75°C =25°C -25°C : R_{DS(on)} [mΩ] 001 10 0.01 0.1 1 10 100 Drain Current: -ID [A]

Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV) 1000 Static Drain - Source On-State Resistance =125°C =75°C _a=25°C -25°C $:R_{\text{DS(on)}}\left[\text{m}\Omega\right]$ 100 10 0.01 0.1 1 10 100 Drain Current: -ID [A]

120 100 Drain Current Dissipation : I_D/I_D max. (%) 80 60 40 20 0 0 25 50 75 100 125 150 175 Junction Temperature : T_i [°C]

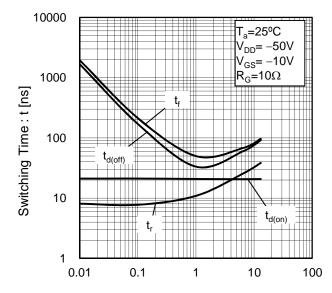
Fig.18 Drain Current Derating Curve

Fig.19 Typical Capacitance vs. Drain - Source Voltage



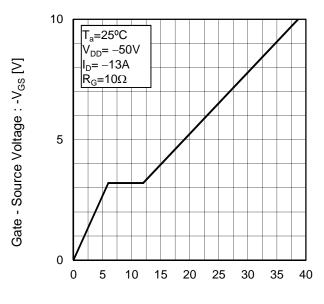
Drain - Source Voltage : -V_{DS} [V]

Fig.20 Switching Characteristics



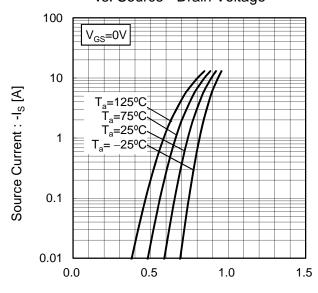
Drain Current : -I_D [A]

Fig.21 Dynamic Input Characteristics

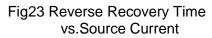


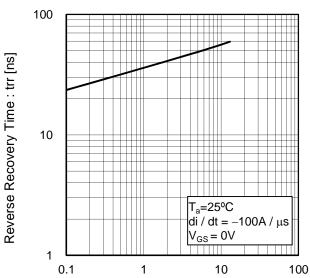
Total Gate Charge : Q_g [nC]

Fig.22 Source Current vs. Source - Drain Voltage



Source-Drain Voltage: -V_{SD} [V]





Source Current : -I_S [A]

●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

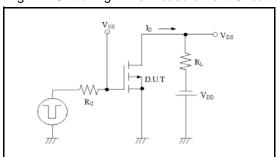


Fig.2-1 Gate Charge Measurement Circuit

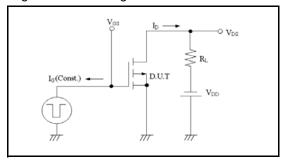


Fig.3-1 Avalanche Measurement Circuit

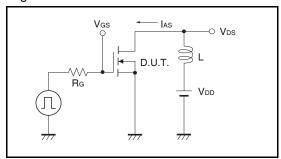


Fig.1-2 Switching Waveforms

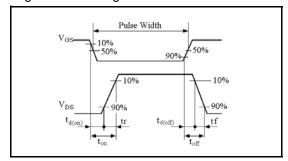


Fig.2-2 Gate Charge Waveform

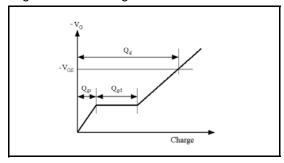
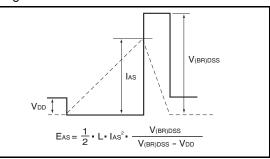
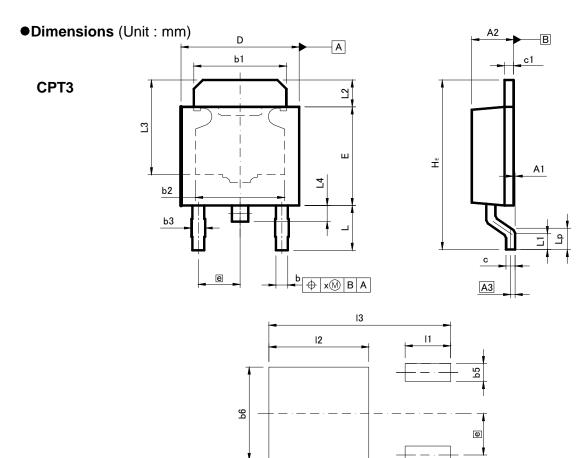


Fig.3-2 Avalanche Waveform





Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMI	MILIMETERS		HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.15	0.000	0.006
A2	2.20	2.50	0.087	0.098
A3	0.2	25	0.0	10
b	0.55	0.75	0.022	0.030
b1	5.00	5.30	0.197	0.209
b2	5.0	00	0.1	97
b3	0.	75	0.0	30
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
е	2.3	30	0.0	91
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.110
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.3	30	0.2	09
L4	0.9	90	0.0	35
Lp	1.00	1.60	0.039	0.063
Х	_	0.25	_	0.010

DIM MILIME		MILIMETERS		HES
DIM	MIN	MAX	MIN	MAX
b5	_	1.00	_	0.04
b6	_	5.20	_	0.205
l1	_	2.50	_	0.098
12	_	5.50	-	0.217
13	_	10.00	-	0.394

Dimension in mm / inches

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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CL ACCIII
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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